PUA3111 (PU3111)

Silicon NPN triple diffusion planar type

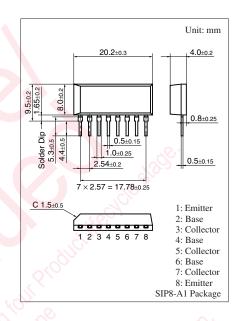
For power amplification/switching Complementary to PUA3211 (PU3211)

Features

- High forward current transfer ratio h_{FE} which has satisfactory linearity
- Low collector-emitter saturation voltage $V_{CE(sat)}$
- NPN 3 elements

Absolute Maximum Ratings $T_C = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	60	V	
Collector-emitter voltage (Base open)	V _{CEO}	60	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I _C	4	Α	
Peak collector current	I _{CP}	8	А	
Collector power dissipation	P _C	15	W	
$T_a = 25^{\circ}C$		2.4		
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	C.	

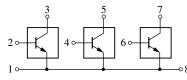


Electrical Characteristics $T_c = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 30 \text{ mA}, I_{\rm B} = 0$	60	die	Č.	V
Base-emitter voltage	V _{BE}	$V_{CE} = 4 V, I_C = 3 A$	Q .	S	2.0	V
Collector-emitter current (E-B short)	I _{CES}	$V_{CE} = 60 \text{ V}, V_{BE} = 0$	1 A		400	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 30 V, I_B = 0$	0.7		700	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 5 V, I_C = 0$			1	mA
Forward current transfer ratio	h _{FE1}	$V_{CE} = 4 V, I_C = 1 A$	40		250	
	h _{FE2}	$V_{CE} = 4 V, I_C = 3 A$	15			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 4 {\rm A}, I_{\rm B} = 0.4 {\rm A}$			1.5	V
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_C = 0.1 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_C = 4 A$		0.3		μs
Storage time	t _{stg}	$I_{B1} = 0.4 \text{ A}, I_{B2} = -0.4 \text{ A}$		1.2		μs
Fall time	t _f	$V_{CC} = 50 V$		0.4		μs

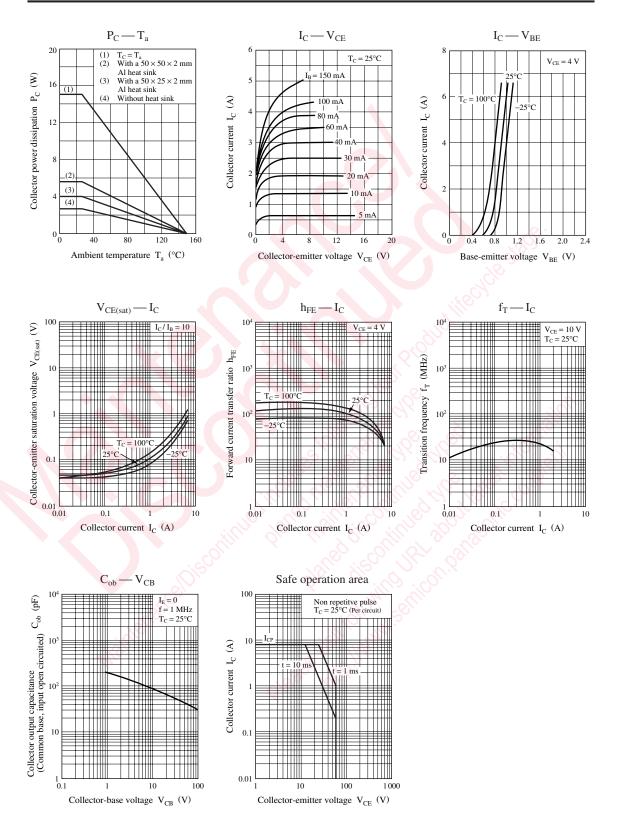
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Internal Connection



Note) The part number in the parenthesis shows conventional part number.

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